FEATURES

- **Single-Chip Mixer/Oscillator and PLL Synthesizer**
- **Three-Band Local Oscillator**
- **I²C Bus Protocol (Bidirectional Data Transmission)**
- **30-V Tuning Voltage Output**
- **Four NPN-Type Band-Switch Drivers**
- **Programmable Reference Divider Ratio (512, 640, or 1024)**
- **5-V Power Supply**
- **30-Pin TSSOP Package**

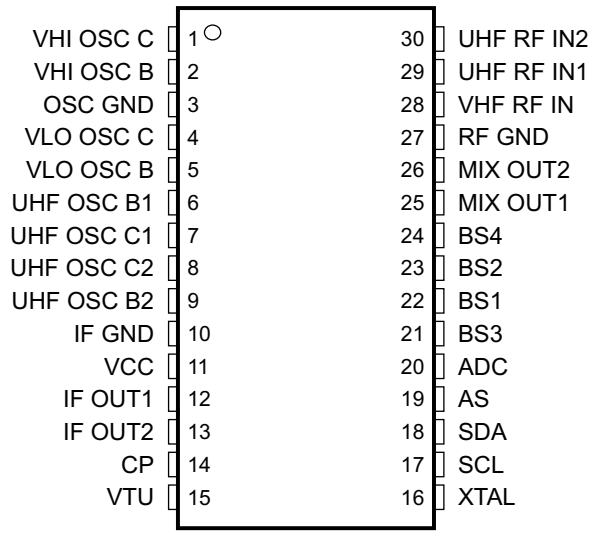
APPLICATIONS

- **TV**
- **VCR/DVD Recorder**
- **Set-Top Box**

DESCRIPTION

The SN761681 is a synthesized tuner IC designed for TV tuning systems. The circuit consists of a PLL synthesizer, three-band local oscillator and mixer, 30-V output tuning amplifier, four NPN band-switch drivers, and is available in a small-outline package. A 15-bit programmable counter and reference divider are controlled by I²C bus protocol. Tuning step frequency is selectable by this reference divider ratio for a crystal oscillator.

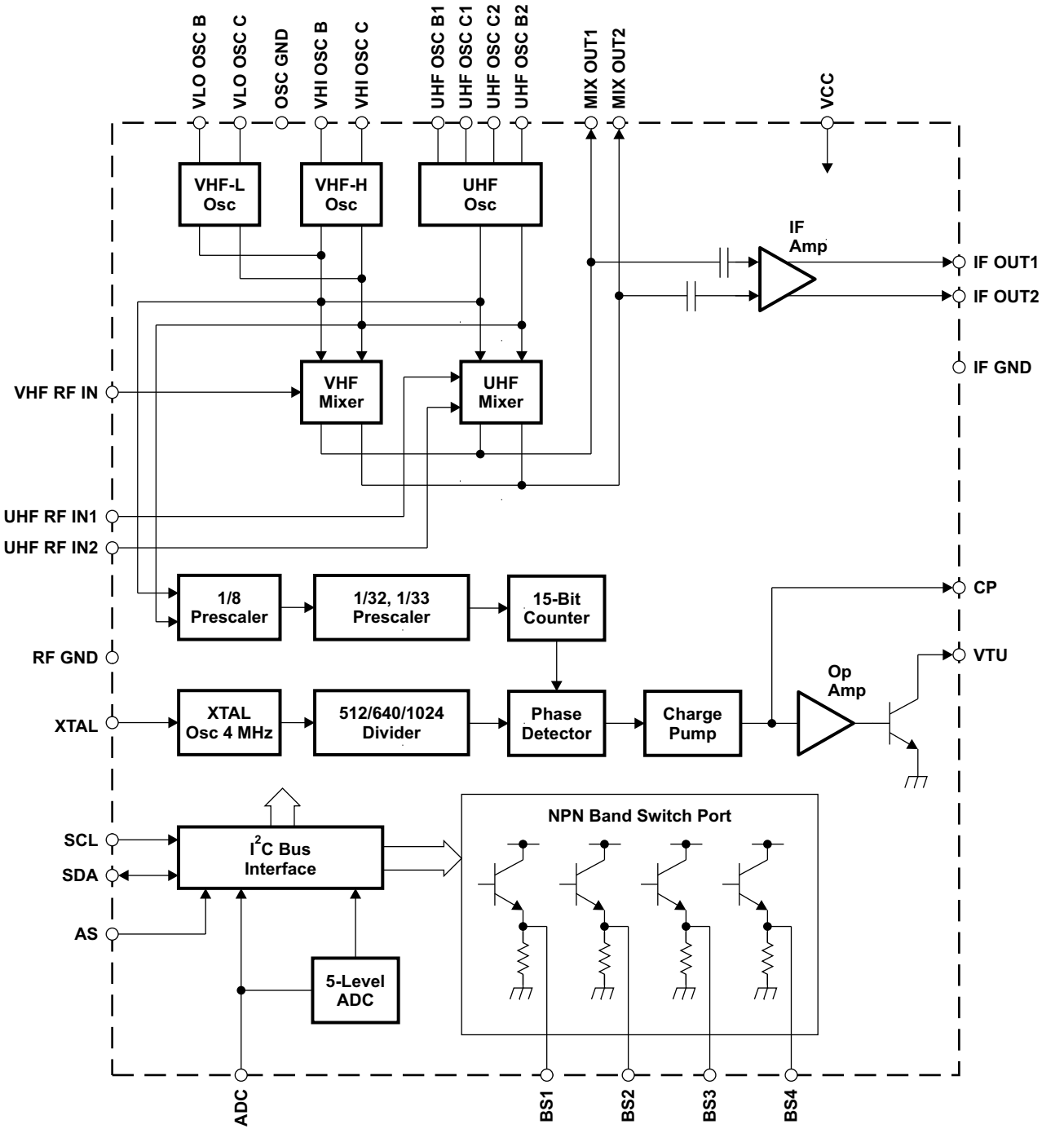
DBT PACKAGE
(TOP VIEW)



P0038-01

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

Functional Block Diagram



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Pin Assignments

Pin Description

TERMINAL NAME	TERMINAL NO.	DESCRIPTION	SCHEMATIC
ADC	20	ADC input	Figure 1
AS	19	Address selection input	Figure 2
BS1	22	Band switch1 output (NPN emitter follower)	Figure 3
BS2	23	Band switch2 output (NPN emitter follower)	Figure 3
BS3	21	Band switch3 output (NPN emitter follower)	Figure 3
BS4	24	Band switch4 output (NPN emitter follower)	Figure 3
CP	14	Charge pump output	Figure 4
IF GND	10	IF ground	
IF OUT1	12	IF output	Figure 5
IF OUT2	13	IF output	Figure 5
MIX OUT1	25	Mixer output	Figure 6
MIX OUT2	26	Mixer output	Figure 6
OSC GND	3	Oscillator ground	
RF GND	27	RF ground	
SCL	17	Serial clock input	Figure 7
SDA	18	Serial data input/output	Figure 8
UHF OSC B1	6	UHF oscillator base1	Figure 9
UHF OSC B2	9	UHF oscillator base2	Figure 9
UHF OSC C1	7	UHF oscillator collector1	Figure 9
UHF OSC C2	8	UHF oscillator collector2	Figure 9
UHF RF IN1	29	UHF RF input	Figure 10
UHF RF IN2	30	UHF RF input	Figure 10
VCC	11	Supply voltage for mixer/oscillator/PLL: 5-V	
VHF RF IN	28	VHF RF input	Figure 11
VHI OSC B	2	VHF HIGH oscillator base	Figure 12
VHI OSC C	1	VHF HIGH oscillator collector	Figure 12
VLO OSC B	5	VHF LOW oscillator base	Figure 13
VLO OSC C	4	VHF LOW oscillator collector	Figure 13
VTU	15	Tuning voltage amplifier output	Figure 14
XTAL	16	4-MHz crystal oscillator input	Figure 15

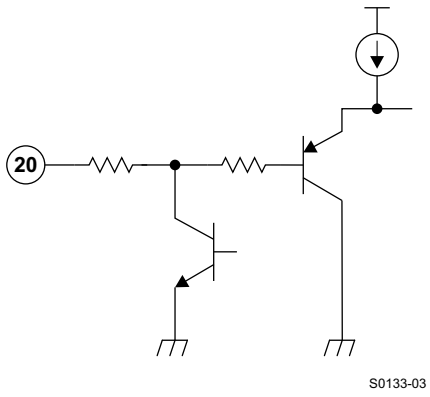


Figure 1.

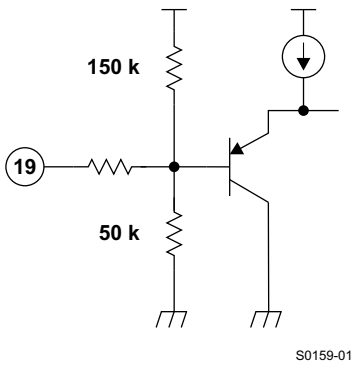


Figure 2.

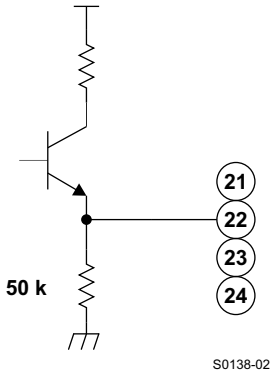


Figure 3.

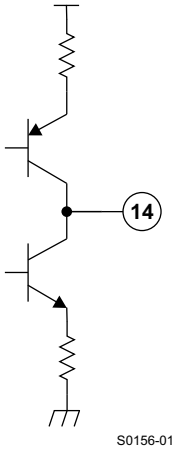


Figure 4.

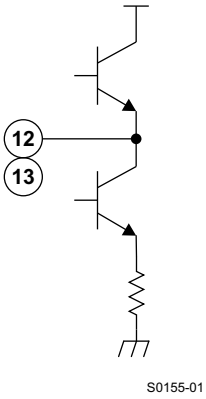


Figure 5.

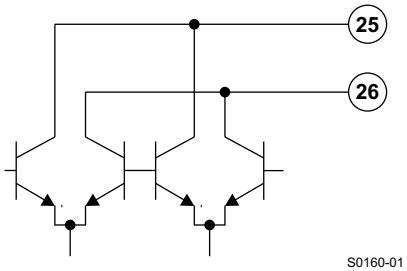


Figure 6.

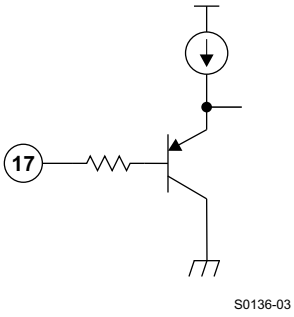


Figure 7.

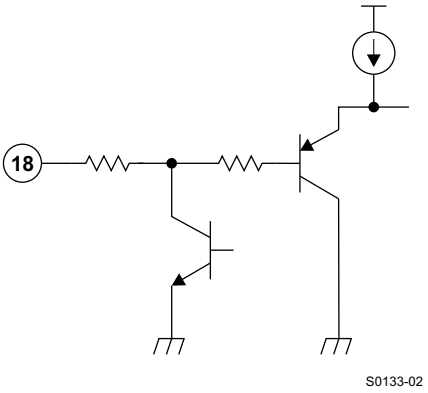


Figure 8.

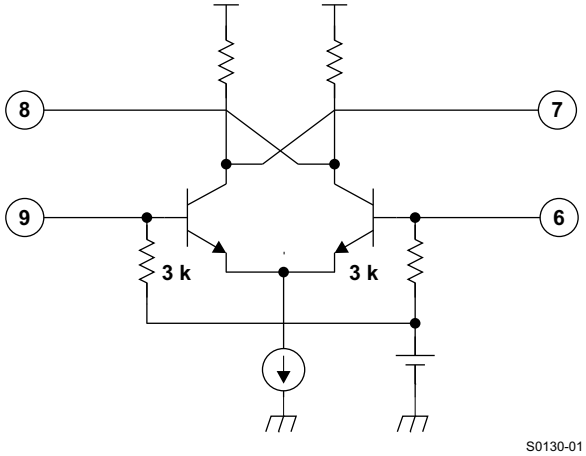


Figure 9.

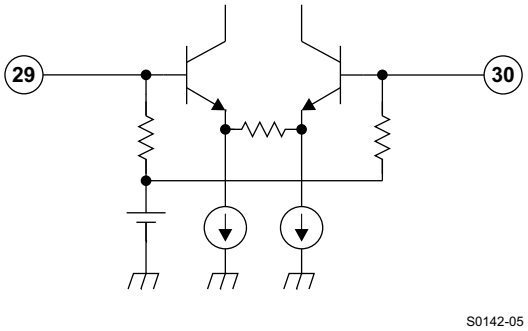


Figure 10.

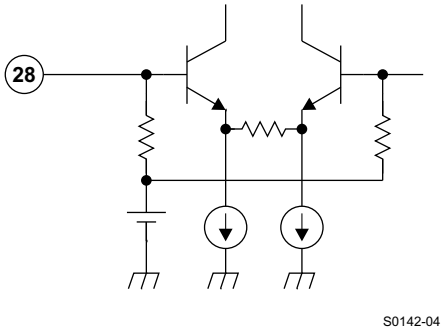


Figure 11.

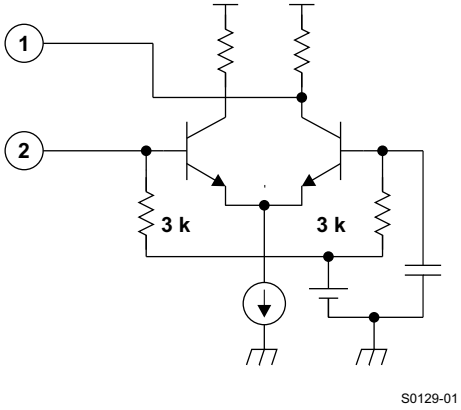


Figure 12.

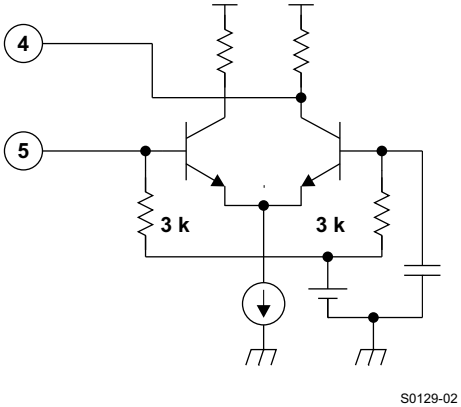


Figure 13.

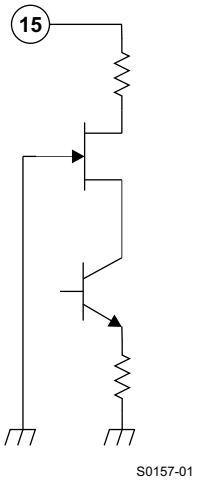


Figure 14.

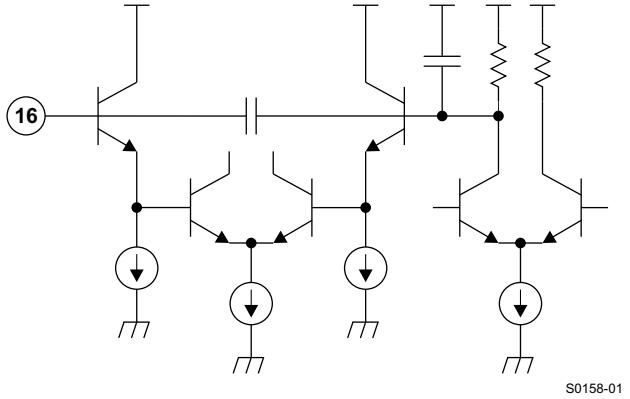


Figure 15.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted) (1)

Supply voltage, V_{CC} (2)	VCC (Pin 11)	–0.4 V to 6.5 V
Input voltage 1, V_{GND} (2)	RF GND, OSC GND (Pins 3, 27)	–0.4 V to 0.4 V
Input voltage 2, V_{VTU} (2)	VTU	–0.4 V to 35 V
Input voltage 3, V_{IN} (2)	Other pins (Pins 1, 2, 4–9, 12–14, 16–26, 28–30)	–0.4 V to 6.5 V
Continuous total dissipation, P_D (3)	$T_A \leq 25°C$	1071 mW
Operating free-air temperature, T_A		–20°C to 85°C
Storage temperature range, T_{stg}		–65°C to 150°C
Maximum junction temperature, T_J		150°C
Maximum short-circuit time, $t_{SC(max)}$	Each pin to V_{CC} or to GND	10 s

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Voltage values are with respect to the IF GND of the circuit.
(3) Derating factor is 8.57 mW/°C for $T_A \geq 25°C$.

RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}		4.5	5	5.5	V
Tuning supply voltage, V_{TU}			30	33	V
Output current of band switch, I_{BS}	One port on			10	mA
Operating free-air temperature, T_A		–20		85	°C

ELECTRICAL CHARACTERISTICS, Total Device and Serial Interface

V_{CC} = 4.5 V to 5.5 V, T_A = –20°C to 85°C, unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$I_{CC}1$	Supply current 1			60		mA
$I_{CC}2$	Supply current 2	One band switch on (I_{BS} = 10 mA)		70		mA
V_{IH}	High-level input voltage (SCL, SDA)		2.8		V_{CC}	V
V_{IL}	Low-level input voltage (SCL, SDA)				1.4	V
I_{IH}	High-level input current (SCL, SDA)				10	µA
I_{IL}	Low-level input current (SCL, SDA)		–10			µA
V_{POR}	Power-on-reset supply voltage (threshold of supply voltage between reset and operation mode)		2.1	2.8	3.5	V
I²C INTERFACE						
V_{ASH}	Address-select high-input voltage (AS)	V_{CC} = 5 V	4.5		5	V
V_{ASM1}	Address-select mid1-input voltage (AS)	V_{CC} = 5 V	2		3	V
V_{ASM2}	Address-select mid2-input voltage (AS)	V_{CC} = 5 V	1		1.5	V
V_{ASL}	Address-select low-input voltage (AS)	V_{CC} = 5 V			0.5	V
I_{ASH}	Address-select high-input current (AS)				140	µA
I_{ASL}	Address-select low-input current (AS)		–50			µA
V_{ADC}	ADC input voltage	See Table 8	0		V_{CC}	V
I_{ADH}	ADC high-level input current	V_{ADC} = V_{CC}			10	µA
I_{ADL}	ADC low-level input current	V_{ADC} = 0 V	–50			µA
V_{OL}	Low-level output voltage (SDA)	V_{CC} = 5 V, I_{OL} = 3 mA			0.4	V
I_{SDAH}	High-level output leakage current (SDA)	V_{SDA} = 5.5 V			10	µA
f_{SCL}	Clock frequency (SCL)			100	400	kHz
	I²C Timing (see timing chart, Figure 16)					
$t_{hd(DAT)}$	Data hold time		0			µs
$t_{(BUF)}$	Bus free time		1.3			µs
$t_{hd(STA)}$	Start hold time		0.6			µs
$t_{(Low)}$	SCL-low hold time		1.3			µs
$t_{(High)}$	SCL-high hold time		0.6			µs
$t_{su(STA)}$	Start setup time		0.6			µs
$t_{su(DAT)}$	Data setup time		0.1			µs
t_r	SCL, SDA rise time				0.3	µs
t_f	SCL, SDA fall time				0.3	µs
$t_{su(STO)}$	Stop setup time		0.6			µs

ELECTRICAL CHARACTERISTICS, PLL and Band Switch

V_{CC} = 4.5 V to 5.5 V, T_A = –20°C to 85°C, unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
N	Divider ratio	15-bit frequency word	256		32767	
f_{XTAL}	Crystal oscillator frequency	R_{XTAL} = 25 Ω to 300 Ω	3.2	4	4.48	MHz
Z_{XTAL}	Crystal oscillator input impedance			1.6		kΩ
V_{IXTAL2}	Minimum reference input sensitivity (XTAL)	4 MHz, ac coupling with 0.1 µF capacitor			100	mVp-p
V_{VTUL}	Tuning amplifier low-level output voltage	R_L = 22 kΩ, V_{TU} = 33 V	0.3	0.4	0.5	V
I_{VTUOFF}	Tuning amplifier leakage current (off)	OS = 1, V_{TU} = 33 V			10	µA
I_{CPH}	Charge-pump high-level input current	CP = 1		280		µA
I_{CPL}	Charge-pump low-level input current	CP = 0		60		µA
V_{CP}	Charge-pump output voltage	PLL locked		1.95		V
I_{CPOFF}	Charge-pump leakage current	T2 = 0, T1 = 1, V_{CP} = 2 V, T_A = 25°C	–15		15	nA
I_{BS}	Band-switch driver output current				10	mA
V_{BS1}	Band-switch driver output voltage	I_{BS} = 10 mA	3			V
V_{BS2}		I_{BS} = 10 mA, V_{CC} = 5 V, T_A = 25°C	3.5	3.9		
I_{BSOFF}	Band-switch driver leakage current	V_{BS} = 0 V			3	µA

ELECTRICAL CHARACTERISTICS, Mixer, Oscillator, IF Amplifier

V_{CC} = 5 V, T_A = 25°C, measured in Figure 17 reference measurement circuit at 50-Ω system,
IF filter characteristics: f_{peak} = 43 MHz (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
G_{c1}	Conversion gain (mixer-IF amplifier), VHF-LOW	f_{in} = 58 MHz (1)	22	25	28	dB
G_{c3}		f_{in} = 130 MHz (1)	22	25	28	
G_{c4}	Conversion gain (mixer-IF amplifier), VHF-HIGH	f_{in} = 136 MHz (1)	22	25	28	dB
G_{c6}		f_{in} = 364 MHz (1)	22	25	28	
G_{c7}	Conversion gain (mixer-IF amplifier), VHF-UHF	f_{in} = 370 MHz (1)	26	29	32	dB
G_{c9}		f_{in} = 804 MHz (1)	25	28	31	
NF_1	Noise figure, VHF-LOW	f_{in} = 55.25 MHz		9.5		dB
NF_3		f_{in} = 127.25 MHz		9.5		
NF_4	Noise figure, VHF-HIGH	f_{in} = 133.25 MHz		10		dB
NF_6		f_{in} = 361.25 MHz		10		
NF_7	Noise figure, UHF	f_{in} = 367.25 MHz		11		dB
NF_9		f_{in} = 801.25 MHz		11		
CM_1	1% cross-modulation distortion, VHF-LOW	f_{in} = 55.25 MHz (2)		89		dBµV
CM_3		f_{in} = 127.25 MHz (2)		89		
CM_4	1% cross-modulation distortion, VHF-HIGH	f_{in} = 133.25 MHz (2)		86		dBµV
CM_6		f_{in} = 361.25 MHz (2)		86		
CM_7	1% cross-modulation distortion, UHF	f_{in} = 367.25MHz (2)		87		dBµV
CM_9		f_{in} = 801.25 MHz (2)		87		
V_{IFO1}	IF output voltage, VHF-LOW	f_{in} = 55.25 MHz (3)		117		dBµV
V_{IFO3}		f_{in} = 127.25 MHz (3)		117		
V_{IFO4}	IF output voltage, VHF-HIGH	f_{in} = 133.25 MHz (3)		117		dBµV
V_{IFO6}		f_{in} = 361.25 MHz (3)		117		
V_{IFO7}	IF output voltage, UHF	f_{in} = 367.25MHz (3)		117		dBµV
V_{IFO9}		f_{in} = 801.25 MHz (3)		117		
Φ_{OSC1}	Phase noise, VHF-LOW	f_{in} = 55.25 MHz (4)		88		dBc/Hz
Φ_{OSC3}		f_{in} = 127.25 MHz (4)		88		
Φ_{OSC4}	Phase noise, VHF-HIGH	f_{in} = 133.25 MHz (4)		86		dBc/Hz
Φ_{OSC6}		f_{in} = 361.25 MHz (4)		86		
Φ_{OSC7}	Phase noise, UHF	f_{in} = 367.25MHz (4)		84		dBc/Hz
Φ_{OSC9}		f_{in} = 801.25 MHz (4)		84		
	Prescaler beat (5)				25	dBµV

(1) IF = 43 MHz, RF input level = 80 dBµV
(2) $f_{undes} = f_{des} \pm 6$ MHz, P_{in} = 80 dBµV, AM 1 kHz, 30%, DES/CM = S/I = 46 dB
(3) IF = 45.75 MHz
(4) Offset = 10 kHz, RF input level = 70 dBµV
(5) Design parameter, not tested

Functional Description

I²C Bus Mode

I²C Write Mode (R/$\overline{W}$ = 0)

Table 1. Write Data Format

	MSB							LSB	(1)
Address byte (ADB)	1	1	0	0	0	MA1	MA0	R/$\overline{W}$ = 0	A
Divider byte 1 (DB1)	0	N14	N13	N12	N11	N10	N9	N8	A
Divider byte 2 (DB2)	N7	N6	N5	N4	N3	N2	N1	N0	A
Control byte (CB)	1	CP	T2	T1	T0	RSA	RSB	OS	A
Band-switch byte (BB)	X	X	X	X	BS4	BS3	BS2	BS1	A

(1) A: Acknowledge

Table 2. Description of Data Symbols

SYMBOL	DESCRIPTION	DEFAULT
MA[1:0]	Address-set bits (see Table 3, *Address Selection*)	
N[14:0]	Programmable counter set bits $N = N14 \times 2^{14} + N13 \times 2^{13} + ... + N1 \times 2 + N0$ Oscillation frequency = $f_r \times 8 \times N$ f_r = Reference frequency = 4 MHz/Reference divider	N14 = N13 = N12 = ... = N0 = 0
CP	Charge-pump current-set bit 60 µA (CP = 0), 280 µA (CP = 1)	CP = 1
T[2:0]	TEST bits (see Table 4, *Test Bits*) Normal mode: T2 = 0, T1 = 0, T0 = 1/0	T[2:0] = 001
RSA, RSB	Reference divider ratio selection bits See Table 6, Reference Divider Ratio.	RSA = 0, RSB = 1
OS	Tuning amplifier control bit Tuning voltage on (OS = 0) Tuning voltage off, high impedance (OS = 1)	OS = 0
BS[4:1]	Band-switch control bits BSn = 0: Tr = OFF BSn = 1: Tr = ON Band selection by BS1, BS2, BS4 **BS1(VL) BS2(VH) BS4(U)** 1 0 0 VHF-LO X 1 0 VHF-HI X X 1 UHF	BSn = 0
X	Don't care	

Table 3. Address Selection

MA1	MA0	Voltage Applied on AS Input
0	0	LOW: 0 V to 0.1 V_{CC}
0	1	MID2: open, or 0.2 V_{CC} to 0.3 V_{CC}
1	0	MID1: 0.4 V_{CC} to 0.6 V_{CC}
1	1	HIGH: 0.9 V_{CC} to V_{CC}

Table 4. Test Bits (1)

T2	T1	T0	Device Operation	Note
0	0	0	Normal operation	
0	0	1	Normal operation	Default
0	1	X	Charge pump is off.	
1	1	0	Charge pump is sink.	
1	1	1	Charge pump is source.	
1	0	X	Test mode	ADC not available

(1) Not used for other bit patterns

Table 5. Reference Divider Ratio

RSA	RSB	Reference Divider Ratio
X	0	640
0	1	1024
1	1	512

I^2C Read Mode (R/W = 1)

Table 6. Read Data Format

	MSB							LSB	(1)
Address byte (ADB)	1	1	0	0	0	MA1	MA0	R/$\overline{W}$ = 1	A
Status byte (SB)	POR	FL	1	1	1	A2	A1	A0	–

(1) A: Acknowledge

Table 7. Description of Data Symbols

SYMBOL	DESCRIPTION	DEFAULT
MA[1:0]	Address-set bits (see Table 3, *Address Selection*)	
POR	Power-on-reset flag POR set: Power on POR reset: End-of-data transmission procedure	POR = 1
FL	In-lock flag PLL locked (FL = 1), PLL unlocked (FL = 0)	
A[2:0]	Digital data of ADC (see Table 8, *ADC Level*)	

Table 8. ADC Level

A2	A1	A0	Voltage Applied on ADC Input(1)
1	0	0	0.6 V_{CC} to V_{CC}
0	1	1	0.45 V_{CC} to 0.6 V_{CC}
0	1	0	0.3 V_{CC} to 0.45 V_{CC}
0	0	1	0.15 V_{CC} to 0.3 V_{CC}
0	0	0	0 V to 0.15 V_{CC}

(1) Accuracy is $0.03 \times V_{CC}$.

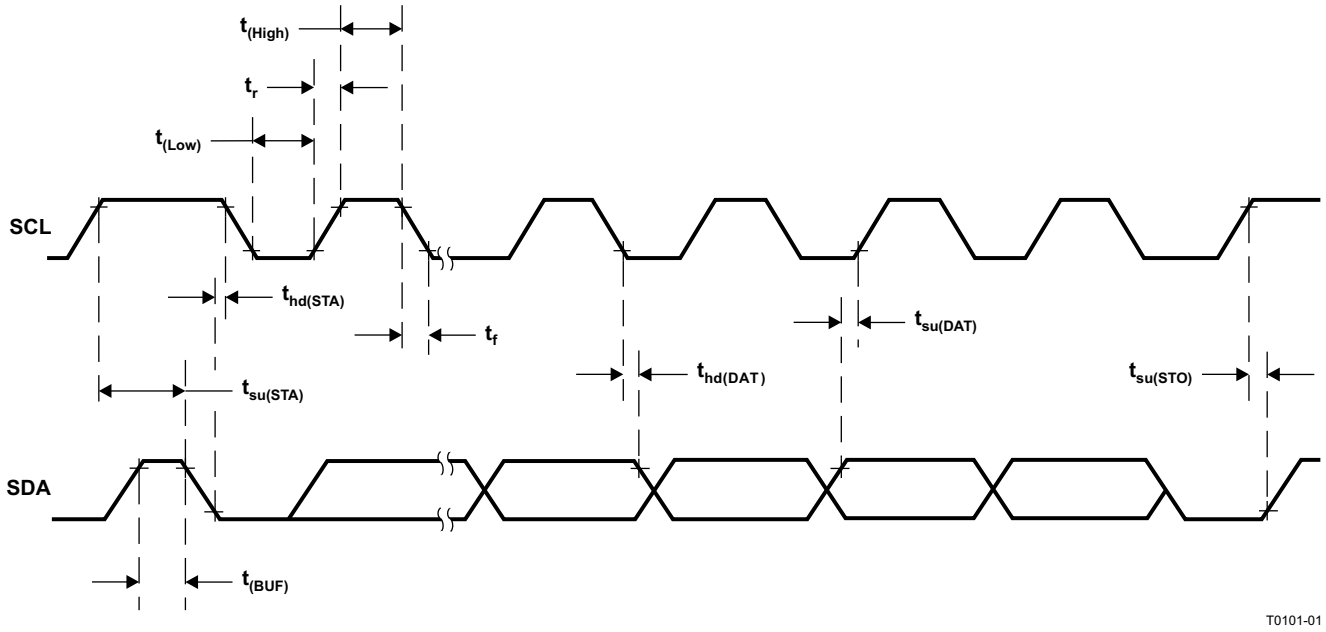
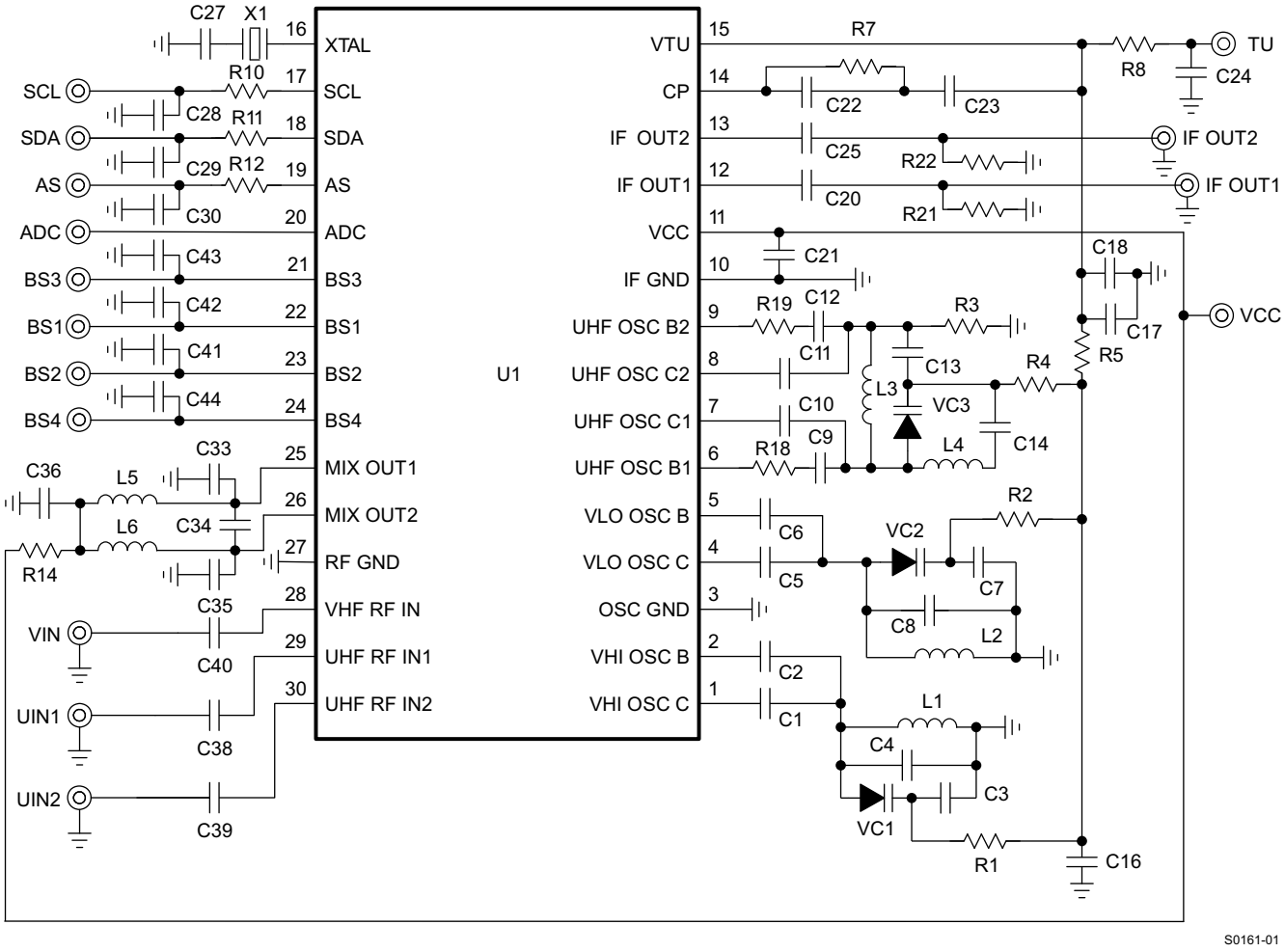


Figure 16. I^2C Timing Chart

APPLICATION INFORMATION

Reference Measurement Circuit



NOTE: This application information is advisory and a performance check is required for actual application circuits. TI assumes no responsibility for the consequences of the use of this circuit nor for any infringement of patent or patent rights of third parties which may result from its use.

Figure 17. Reference Measurement Circuit

APPLICATION INFORMATION (continued)

Component Values for Measurement Circuit

PART NAME	VALUE	PART NAME	VALUE
C1 (VHI OSC C)	3 pF	C39 (UIN2)	2.2 nF
C2 (VHI OSC B)	2 pF	C40 (VIN)	2.2 nF
C3 (VHI OSC)	68 pF	C41 (BS2)	2.2 nF
C4 (VHI OSC)	Open	C42 (BS1)	2.2 nF
C5 (VLO OSC C)	1 pF	C43 (BS3)	2.2 nF
C6 (VLO OSC B)	1 pF	C44 (BS4)	2.2 nF
C7 (VLO OSC)	47 pF	L1 (VHI OSC)	ϕ2,4 mm, 4T, wire 0,4 mm
C8 (VLO OSC)	3 pF	L2 (VLO OSC)	ϕ3 mm, 8T, wire 0,32 mm
C9 (UHF OSC B1)	1.5 pF	L3 (UHF OSC)	ϕ3 mm, 2T, wire 0,4 mm
C10 (UHF OSC C1)	1.5 pF	L4 (UHF OSC)	ϕ2 mm, 3T, wire 0,4 mm
C11 (UHF OSC C2)	1.5 pF	L5 (MIXOUT)	ϕ2,4 mm, 16T, wire 0,26 mm
C12 (UHF OSC B2)	1.5 pF	L6 (MIXOUT)	ϕ2,4 mm, 16T, wire 0,26 mm
C13 (UHF OSC)	12 pF	R1(VHI OSC)	33 kΩ
C14 (UHF OSC)	100 pF	R2 (VLO OSC)	33 kΩ
C16 (VTU)	2.2 nF/50 V	R3 (UHF OSC)	22 kΩ
C17 (VTU)	2.2 nF/50 V	R4 (UHF OSC)	33 kΩ
C18 (VTU)	2.2 nF/50 V	R5 (VTU)	22 kΩ
C20 (IF OUT1)	2.2 nF	R7 (CP)	22 kΩ
C21 (VCC)	4.7 nF	R8 (VTU)	22 kΩ
C22 (CP)	2.2 nF	R10 (SCL)	330 Ω
C23 (CP)	0.1 µF/50 V	R11 (SDA)	330 Ω
C24 (VTU)	2.2 nF/50 V	R12 (AS)	330 Ω
C25 (IF OUT2)	2.2 nF	R14 (MIXOUT)	0
C27 (XTAL)	68 pF	R18 (UHF OSC)	0
C28 (SCL)	Open	R19 (UHF OSC)	0
C29 (SDA)	Open	R21 (IF OUT1)	Open
C30 (AS)	Open	R22 (IF OUT2)	51 Ω
C33 (MIXOUT)	Open	U1	SN761681
C34 (MIXOUT)	22 pF	VC1 (VHI OSC)	1T363A
C35 (MIXOUT)	Open	VC2 (VLO OSC)	1T363A
C36 (MIXOUT)	4.7 nF	VC3 (UHF OSC)	1T363A
C38 (UIN1)	2.2 nF	X1	4-MHz crystal

Test Circuits

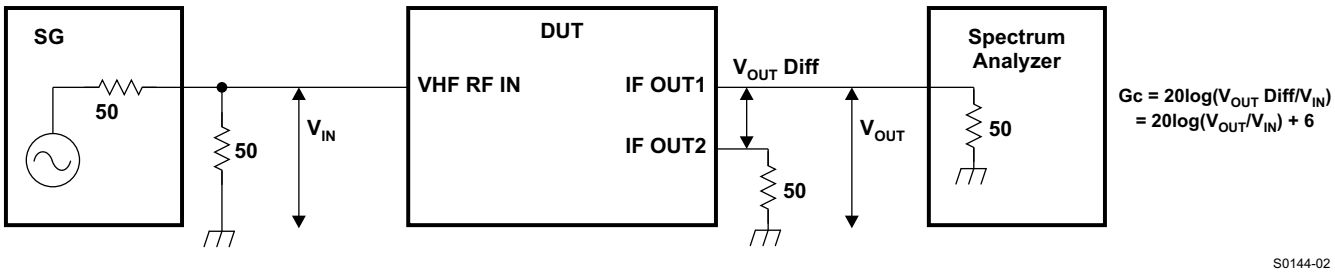


Figure 18. VHF-Conversion Gain-Measurement Circuit

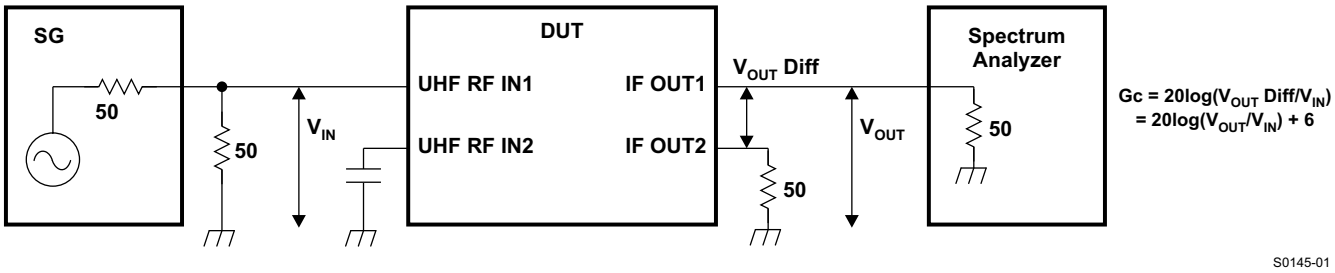


Figure 19. UHF-Conversion Gain-Measurement Circuit

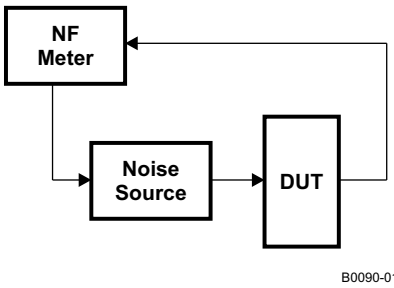


Figure 20. Noise-Figure Measurement Circuit

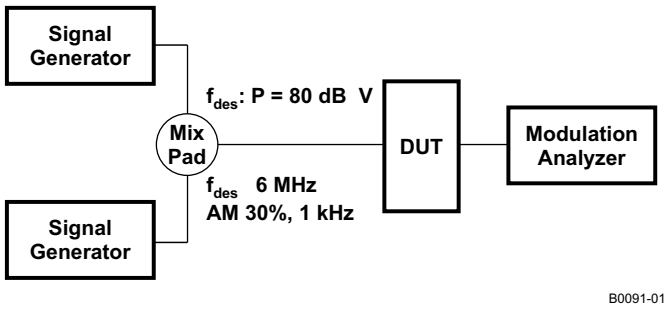


Figure 21. 1% Cross-Modulation Distortion Measurement Circuit

TYPICAL CHARACTERISTICS

Band-Switch Driver Output Voltage (BS1–BS4)

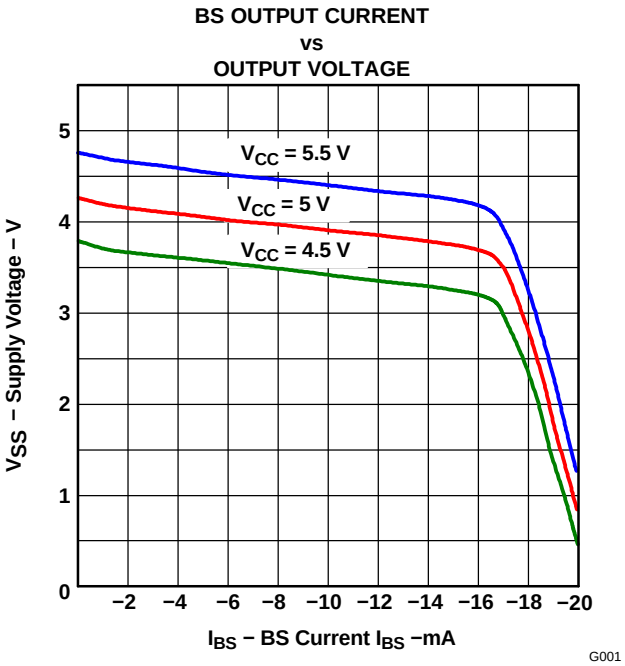


Figure 22. Band-Switch Driver Output Voltage

S-Parameter

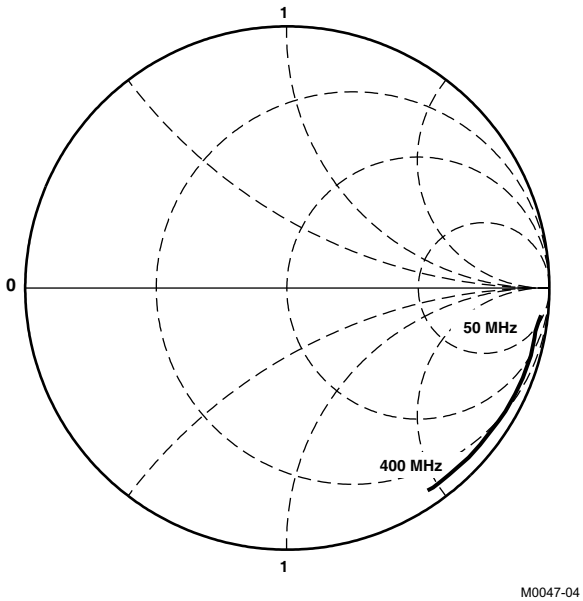


Figure 23. VHF Input

TYPICAL CHARACTERISTICS (continued)

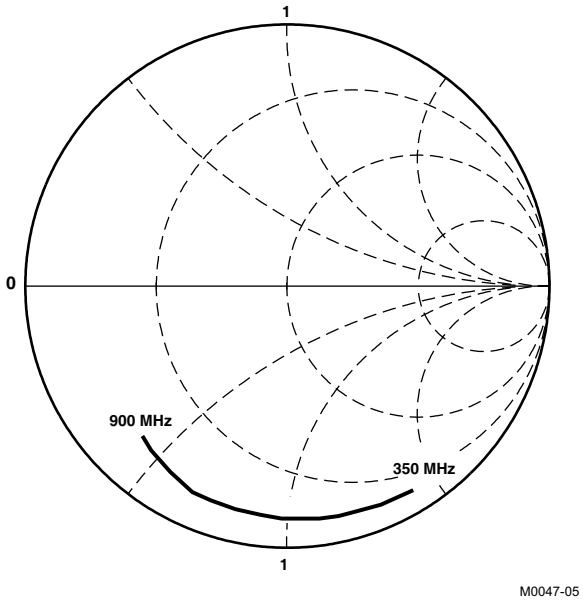


Figure 24. UHF Input

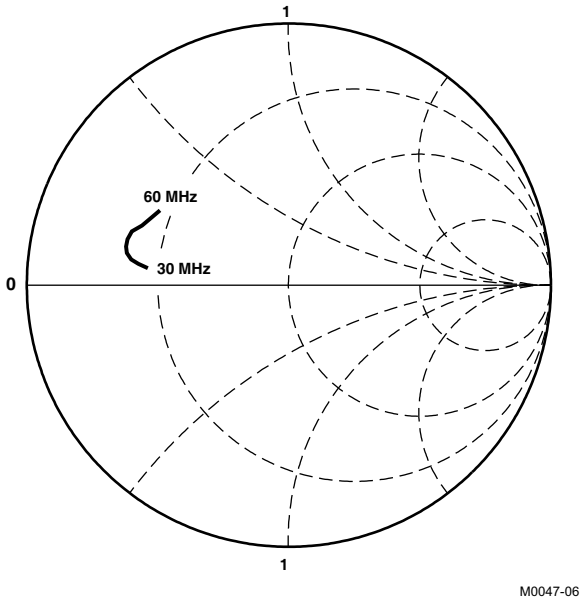


Figure 25. IF Output

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/ Ball Finish	MSL Peak Temp (3)	Samples (Requires Login)
SN761681DBT	OBSOLETE	TSSOP	DBT	30		TBD	Call TI	Call TI	
SN761681DBTG4	OBSOLETE	TSSOP	DBT	30		TBD	Call TI	Call TI	
SN761681DBTR	NRND	TSSOP	DBT	30	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
SN761681DBTRG4	NRND	TSSOP	DBT	30	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

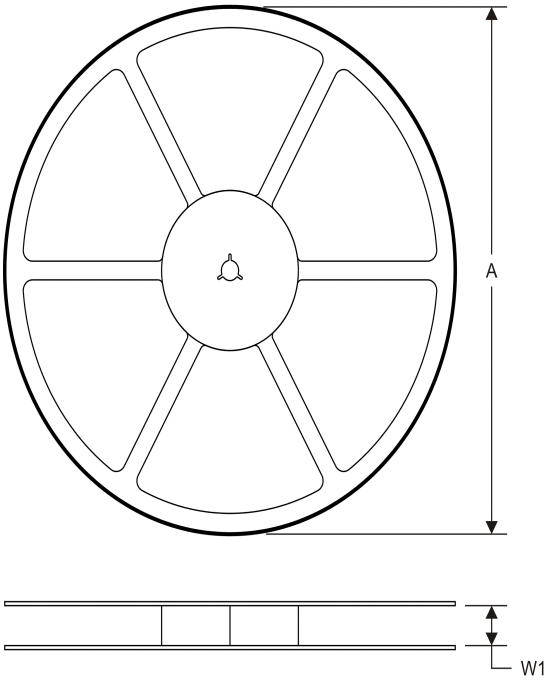
(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

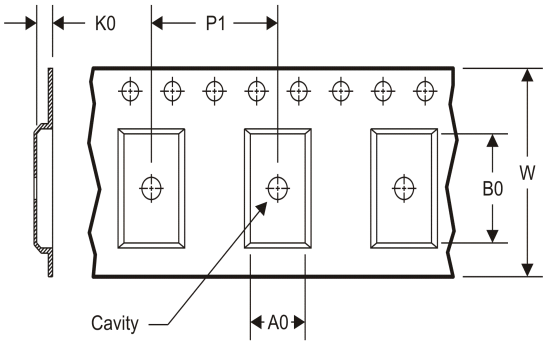
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



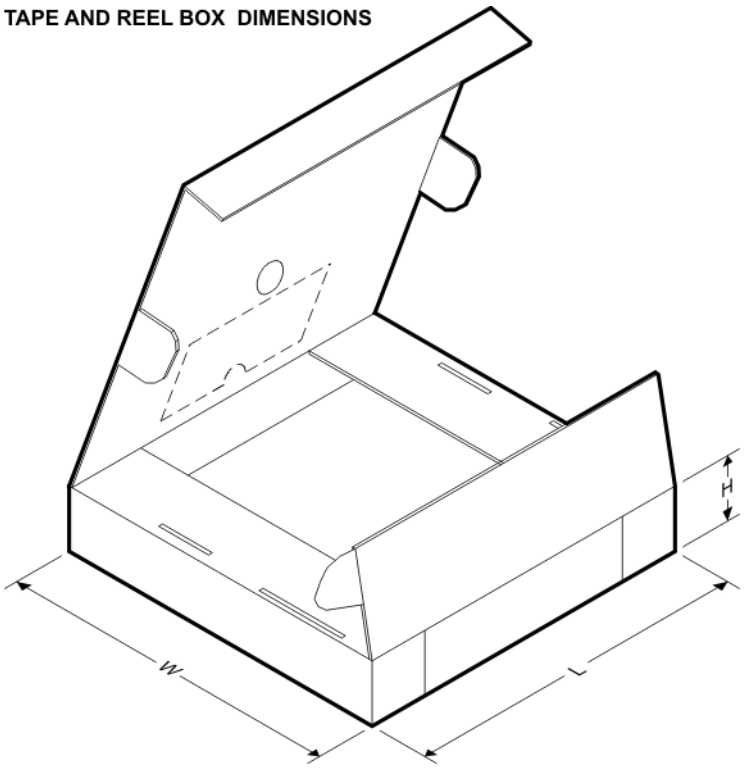
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN761681DBTR	TSSOP	DBT	30	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1

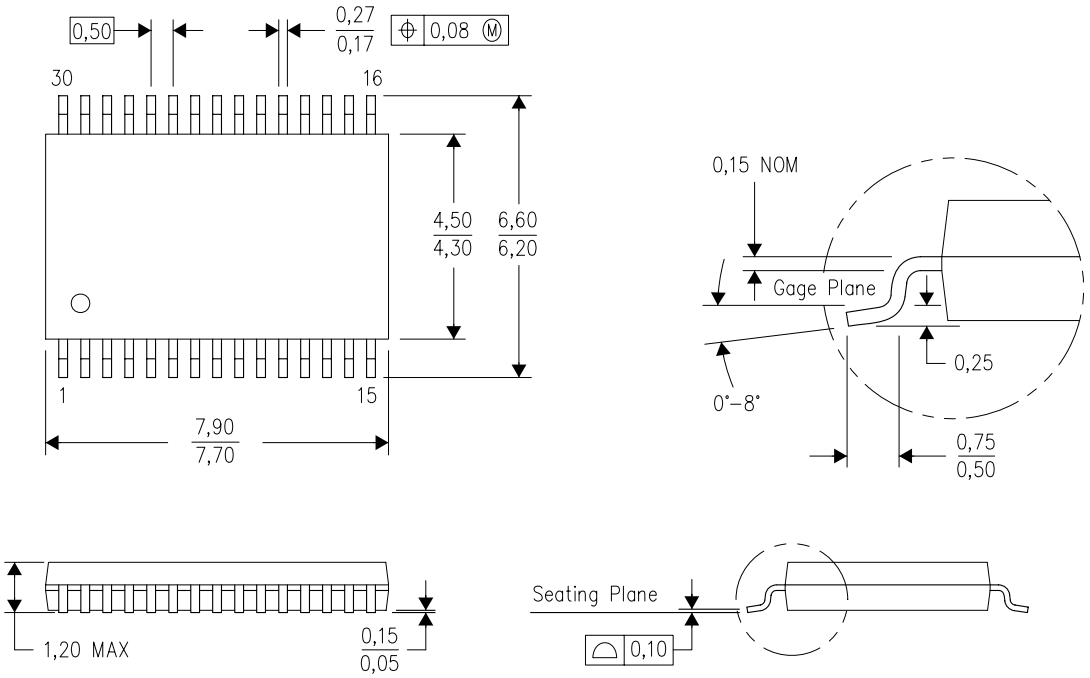
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN761681DBTR	TSSOP	DBT	30	2000	367.0	367.0	38.0

DBT (R–PDSO–G30) PLASTIC SMALL OUTLINE



4073252–5/I 03/11

NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion.
D. Falls within JEDEC MO–153.

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